Welcome to E-XFL.COM

What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	-
Core Size	-
Speed	-
Connectivity	-
Peripherals	-
Number of I/O	-
Program Memory Size	-
Program Memory Type	-
EEPROM Size	-
RAM Size	-
Voltage - Supply (Vcc/Vdd)	-
Data Converters	-
Oscillator Type	-
Operating Temperature	-
Mounting Type	-
Package / Case	-
Supplier Device Package	-
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/c161olmhafxuma1

Table 2 Pin Definitions and Functions

Symbol	Pin Num	Input Outp.	Function
XTAL1	2	I	XTAL1: Input to the oscillator amplifier and input to the internal clock generator
XTAL2	3	O	XTAL2: Output of the oscillator amplifier circuit. To clock the device from an external source, drive XTAL1, while leaving XTAL2 unconnected. Minimum and maximum high/low and rise/fall times specified in the AC Characteristics must be observed.
P3		IO	Port 3 is a 12-bit bidirectional I/O port. It is bit-wise programmable for input or output via direction bits. For a pin configured as input, the output driver is put into high-impedance state. Port 3 outputs can be configured as push/pull or open drain drivers. The Port 3 pins serve for following alternate functions:
P3.2	5	I	CAPIN GPT2 Register CAPREL Capture Input *This alternate input is **only available in the C161O**.*
P3.3	6	O	T3OUT GPT1 Timer T3 Toggle Latch Output
P3.4	7	I	T3EUD GPT1 Timer T3 External Up/Down Control Input
P3.5	8	I	T4IN GPT1 Timer T4 Count/Gate/Reload/Capture Inp
P3.6	9	I	T3IN GPT1 Timer T3 Count/Gate Input
P3.7	10	I	T2IN GPT1 Timer T2 Count/Gate/Reload/Capture Inp
P3.8	11	I/O	MRST SSC Master-Receive/Slave-Transmit Inp./Outp.
P3.9	12	I/O	MTSR SSC Master-Transmit/Slave-Receive Outp./Inp.
P3.10	13	O	TxD0 ASC0 Clock/Data Output (Async./Sync.)
P3.11	14	I/O	RxD0 ASC0 Data Input (Async.) or Inp./Outp. (Sync.)
P3.12	15	O	$\overline{\text{BHE}}$ External Memory High Byte Enable Signal,
		O	$\overline{\text{WRH}}$ External Memory High Byte Write Strobe
P3.13	16	I/O	SCLK SSC Master Clock Output / Slave Clock Input
P4		IO	Port 4 is a 6-bit bidirectional I/O port. It is bit-wise programmable for input or output via direction bits. For a pin configured as input, the output driver is put into high-impedance state. Port 4 can be used to output the segment address lines:
P4.0	17	O	A16 Least Significant Segment Address Line
P4.1	18	O	A17 Segment Address Line
P4.2	19	O	A18 Segment Address Line
P4.3	20	O	A19 Segment Address Line
P4.4	23	O	A20 Segment Address Line
P4.5	24	O	A21 Most Significant Segment Address Line

Table 2 Pin Definitions and Functions (cont'd)

Symbol	Pin Num	Input Outp.	Function
P2		IO	Port 2 is a 7-bit bidirectional I/O port. It is bit-wise programmable for input or output via direction bits. For a pin configured as input, the output driver is put into high-impedance state. Port 2 outputs can be configured as push/pull or open drain drivers. The following Port 2 pins serve for alternate functions:
P2.9	72	I	EX1IN Fast External Interrupt 1 Input
P2.10	73	I	EX2IN Fast External Interrupt 2 Input
P2.11	74	I	EX3IN Fast External Interrupt 3 Input
P2.12	75	I	EX4IN Fast External Interrupt 4 Input
	76	I	EX5IN Fast External Interrupt 5 Input
	77	I	EX6IN Fast External Interrupt 6 Input
	78	I	EX7IN Fast External Interrupt 7 Input *These external interrupts are **only available in the C161O**.*
P5		I	Port 5 is a 2-bit input-only port with Schmitt-Trigger char. The pins of Port 5 also serve as timer inputs:
P5.14	79	I	T4EUD GPT1 Timer T4 External Up/Down Control Input
P5.15	80	I	T2EUD GPT1 Timer T2 External Up/Down Control Input
V_{DD}	4, 22, 37, 64	–	Digital Supply Voltage: + 5 V or + 3 V during normal operation and idle mode. ≥ 2.5 V during power down mode.
V_{SS}	1, 21, 38, 63	–	Digital Ground.

Note: The following behavioral differences must be observed when the bidirectional reset is active:

- Bit BDRSTEN in register SYSCON cannot be changed after EINIT and is cleared automatically after a reset.
- The reset indication flags always indicate a long hardware reset.
- The PORT0 configuration is treated like on a hardware reset. Especially the bootstrap loader may be activated when P0L.4 is low.
- Pin $\overline{\text{RSTIN}}$ may only be connected to external reset devices with an open drain output driver.
- A short hardware reset is extended to the duration of the internal reset sequence.

Memory Organization

The memory space of the C161K/O is configured in a Von Neumann architecture which means that code memory, data memory, registers and I/O ports are organized within the same linear address space which includes 16 MBytes. The entire memory space can be accessed bytewise or wordwise. Particular portions of the on-chip memory have additionally been made directly bitaddressable.

The C161K/O is prepared to incorporate on-chip program memory (not in the ROM-less derivatives, of course) for code or constant data. The internal ROM area can be mapped either to segment 0 or segment 1.

On-chip Internal RAM (IRAM) is provided (1 KByte in the C161K, 2 KBytes in the C161O) as a storage for user defined variables, for the system stack, general purpose register banks and even for code. A register bank can consist of up to 16 wordwide (R0 to R15) and/or bytewide (RL0, RH0, …, RL7, RH7) so-called General Purpose Registers (GPRs).

1024 bytes (2×512 bytes) of the address space are reserved for the Special Function Register areas (SFR space and ESFR space). SFRs are wordwide registers which are used for controlling and monitoring functions of the different on-chip units. Unused SFR addresses are reserved for future members of the C166 Family.

In order to meet the needs of designs where more memory is required than is provided on chip, up to 4 MBytes of external RAM and/or ROM can be connected to the microcontroller.

Central Processing Unit (CPU)

The main core of the CPU consists of a 4-stage instruction pipeline, a 16-bit arithmetic and logic unit (ALU) and dedicated SFRs. Additional hardware has been spent for a separate multiply and divide unit, a bit-mask generator and a barrel shifter.

Based on these hardware provisions, most of the C161K/O's instructions can be executed in just one machine cycle which requires 80 ns at 25 MHz CPU clock. For example, shift and rotate instructions are always processed during one machine cycle independent of the number of bits to be shifted. All multiple-cycle instructions have been optimized so that they can be executed very fast as well: branches in 2 cycles, a 16 × 16 bit multiplication in 5 cycles and a 32-/16 bit division in 10 cycles. Another pipeline optimization, the so-called 'Jump Cache', allows reducing the execution time of repeatedly performed jumps in a loop from 2 cycles to 1 cycle.

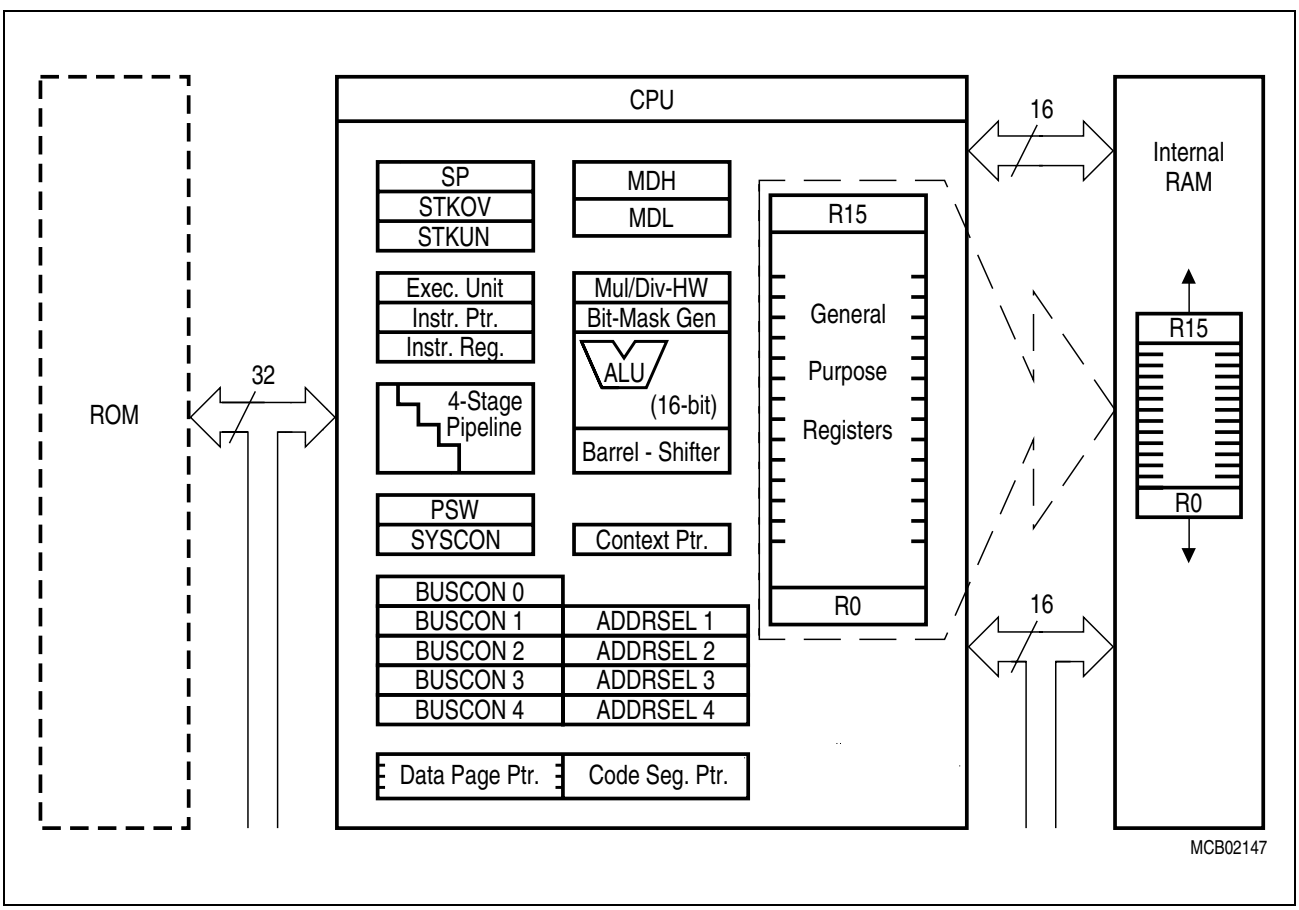

Figure 4 CPU Block Diagram

Table 3 C161K/O Interrupt Nodes

Source of Interrupt or PEC Service Request	Request Flag	Enable Flag	Interrupt Vector	Vector Location	Trap Number
External Interrupt 1	CC9IR	CC9IE	CC9INT	$00'0064_H$	19_H
External Interrupt 2	CC10IR	CC10IE	CC10INT	$00'0068_H$	$1A_H$
External Interrupt 3	CC11IR	CC11IE	CC11INT	$00'006C_H$	$1B_H$
External Interrupt 4	CC12IR	CC12IE	CC12INT	$00'0070_H$	$1C_H$
External Interrupt 5	CC13IR	CC13IE	CC13INT	$00'0074_H$	$1D_H$
External Interrupt 6	CC14IR	CC14IE	CC14INT	$00'0078_H$	$1E_H$
External Interrupt 7	CC15IR	CC15IE	CC15INT	$00'007C_H$	$1F_H$
GPT1 Timer 2	T2IR	T2IE	T2INT	$00'0088_H$	22_H
GPT1 Timer 3	T3IR	T3IE	T3INT	$00'008C_H$	23_H
GPT1 Timer 4	T4IR	T4IE	T4INT	$00'0090_H$	24_H
GPT2 Timer 5	T5IR	T5IE	T5INT	$00'0094_H$	25_H
GPT2 Timer 6	T6IR	T6IE	T6INT	$00'0098_H$	26_H
GPT2 CAPREL Reg.	CRIR	CRIE	CRINT	$00'009C_H$	27_H
ASC0 Transmit	S0TIR	S0TIE	S0TINT	$00'00A8_H$	$2A_H$
ASC0 Transmit Buffer	S0TBIR	S0TBIE	S0TBINT	$00'011C_H$	47_H
ASC0 Receive	S0RIR	S0RIE	S0RINT	$00'00AC_H$	$2B_H$
ASC0 Error	S0EIR	S0EIE	S0EINT	$00'00B0_H$	$2C_H$
SSC Transmit	SCTIR	SCTIE	SCTINT	$00'00B4_H$	$2D_H$
SSC Receive	SCRIR	SCRIE	SCRINT	$00'00B8_H$	$2E_H$
SSC Error	SCEIR	SCEIE	SCEINT	$00'00BC_H$	$2F_H$

*Note: The shaded interrupt nodes are **only available in the C161O**, not in the C161K.*

Special Function Registers Overview

The following table lists all SFRs which are implemented in the C161K/O in alphabetical order.
Bit-addressable SFRs are marked with the letter "**b**" in column "Name". SFRs within the **Extended SFR-Space** (ESFRs) are marked with the letter "**E**" in column "Physical Address". Registers within on-chip X-peripherals are marked with the letter "**X**" in column "Physical Address".

An SFR can be specified via its individual mnemonic name. Depending on the selected addressing mode, an SFR can be accessed via its physical address (using the Data Page Pointers), or via its short 8-bit address (without using the Data Page Pointers).

*Note: The shaded registers are **only available in the C161O**, not in the C161K.*

Table 6 C161K/O Registers, Ordered by Name

Name	Physical Address	8-Bit Addr.	Description	Reset Value
ADDRSEL1	$FE18_H$	$0C_H$	Address Select Register 1	0000_H
ADDRSEL2	$FE1A_H$	$0D_H$	Address Select Register 2	0000_H
ADDRSEL3	$FE1C_H$	$0E_H$	Address Select Register 3	0000_H
ADDRSEL4	$FE1E_H$	$0F_H$	Address Select Register 4	0000_H
BUSCON0 b	$FF0C_H$	86_H	Bus Configuration Register 0	$0XX0_H$
BUSCON1 b	$FF14_H$	$8A_H$	Bus Configuration Register 1	0000_H
BUSCON2 b	$FF16_H$	$8B_H$	Bus Configuration Register 2	0000_H
BUSCON3 b	$FF18_H$	$8C_H$	Bus Configuration Register 3	0000_H
BUSCON4 b	$FF1A_H$	$8D_H$	Bus Configuration Register 4	0000_H
CAPREL	$FE4A_H$	25_H	GPT2 Capture/Reload Register	0000_H
CC10IC b	$FF8C_H$	$C6_H$	EX2IN Interrupt Control Register	0000_H
CC11IC b	$FF8E_H$	$C7_H$	EX3IN Interrupt Control Register	0000_H
CC12IC b	$FF90_H$	$C8_H$	EX4IN Interrupt Control Register	0000_H
CC13IC b	$FF92_H$	$C9_H$	EX5IN Interrupt Control Register	0000_H
CC14IC b	$FF94_H$	CA_H	EX6IN Interrupt Control Register	0000_H
CC15IC b	$FF96_H$	CB_H	EX7IN Interrupt Control Register	0000_H
CC9IC b	$FF8A_H$	$C5_H$	EX1IN Interrupt Control Register	0000_H
CP	$FE10_H$	08_H	CPU Context Pointer Register	$FC00_H$
CRIC b	$FF6A_H$	$B5_H$	GPT2 CAPREL Interrupt Ctrl. Reg.	0000_H
CSP	$FE08_H$	04_H	CPU Code Seg. Pointer Reg. (read only)	0000_H

Table 6 C161K/O Registers, Ordered by Name (cont'd)

Name		Physical Address		8-Bit Addr.	Description	Reset Value
DP0H	**b**	$F102_H$	**E**	81_H	P0H Direction Control Register	00_H
DP0L	**b**	$F100_H$	**E**	80_H	P0L Direction Control Register	00_H
DP1H	**b**	$F106_H$	**E**	83_H	P1H Direction Control Register	00_H
DP1L	**b**	$F104_H$	**E**	82_H	P1L Direction Control Register	00_H
DP2	**b**	$FFC2_H$		$E1_H$	Port 2 Direction Control Register	0000_H
DP3	**b**	$FFC6_H$		$E3_H$	Port 3 Direction Control Register	0000_H
DP4	**b**	$FFCA_H$		$E5_H$	Port 4 Direction Control Register	00_H
DP6	**b**	$FFCE_H$		$E7_H$	Port 6 Direction Control Register	00_H
DPP0		$FE00_H$		00_H	CPU Data Page Pointer 0 Reg. (10 bits)	0000_H
DPP1		$FE02_H$		01_H	CPU Data Page Pointer 1 Reg. (10 bits)	0001_H
DPP2		$FE04_H$		02_H	CPU Data Page Pointer 2 Reg. (10 bits)	0002_H
DPP3		$FE06_H$		03_H	CPU Data Page Pointer 3 Reg. (10 bits)	0003_H
EXICON	**b**	$F1C0_H$	**E**	$E0_H$	External Interrupt Control Register	0000_H
IDCHIP		$F07C_H$	**E**	$3E_H$	Identifier	$05XX_H$
IDMANUF		$F07E_H$	**E**	$3F_H$	Identifier	1820_H
IDMEM		$F07A_H$	**E**	$3D_H$	Identifier	0000_H
IDMEM2		$F076_H$	**E**	$3B_H$	Identifier	0000_H
IDPROG		$F078_H$	**E**	$3C_H$	Identifier	0000_H
MDC	**b**	$FF0E_H$		87_H	CPU Multiply Divide Control Register	0000_H
MDH		$FE0C_H$		06_H	CPU Multiply Divide Reg. – High Word	0000_H
MDL		$FE0E_H$		07_H	CPU Multiply Divide Reg. – Low Word	0000_H
ODP2	**b**	$F1C2_H$	**E**	$E1_H$	Port 2 Open Drain Control Register	0000_H
ODP3	**b**	$F1C6_H$	**E**	$E3_H$	Port 3 Open Drain Control Register	0000_H
ODP6	**b**	$F1CE_H$	**E**	$E7_H$	Port 6 Open Drain Control Register	00_H
ONES	**b**	$FF1E_H$		$8F_H$	Constant Value 1's Register (read only)	$FFFF_H$
P0H	**b**	$FF02_H$		81_H	Port 0 High Reg. (Upper half of PORT0)	00_H
P0L	**b**	$FF00_H$		80_H	Port 0 Low Reg. (Lower half of PORT0)	00_H
P1H	**b**	$FF06_H$		83_H	Port 1 High Reg. (Upper half of PORT1)	00_H
P1L	**b**	$FF04_H$		82_H	Port 1 Low Reg.(Lower half of PORT1)	00_H
P2	**b**	$FFC0_H$		$E0_H$	Port 2 Register	0000_H

Parameter Interpretation

The parameters listed in the following partly represent the characteristics of the C161K/O and partly its demands on the system. To aid in interpreting the parameters right, when evaluating them for a design, they are marked in column “Symbol”:

CC (**C**ontroller **C**haracteristics):
The logic of the C161K/O will provide signals with the respective timing characteristics.

SR (**S**ystem **R**equirement):
The external system must provide signals with the respective timing characteristics to the C161K/O.

DC Characteristics (Standard Supply Voltage Range)

(Operating Conditions apply)[1)]

Parameter	Symbol	Limit Values		Unit	Test Condition
		min.	max.		
Input low voltage (TTL, all except XTAL1)	V_{IL} SR	-0.5	0.2 V_{DD} - 0.1	V	–
Input low voltage XTAL1	V_{IL2} SR	-0.5	0.3 V_{DD}	V	–
Input high voltage (TTL, all except $\overline{\text{RSTIN}}$ and XTAL1)	V_{IH} SR	0.2 V_{DD} + 0.9	V_{DD} + 0.5	V	–
Input high voltage $\overline{\text{RSTIN}}$ (when operated as input)	V_{IH1} SR	0.6 V_{DD}	V_{DD} + 0.5	V	–
Input high voltage XTAL1	V_{IH2} SR	0.7 V_{DD}	V_{DD} + 0.5	V	–
Output low voltage ($\overline{\text{PORT0}}$, $\overline{\text{PORT1}}$, Port 4, ALE, $\overline{\text{RD}}$, $\overline{\text{WR}}$, $\overline{\text{BHE}}$, $\overline{\text{RSTOUT}}$, $\overline{\text{RSTIN}}$[2)])	V_{OL} CC	–	0.45	V	I_{OL} = 2.4 mA
Output low voltage (all other outputs)	V_{OL1} CC	–	0.45	V	I_{OL} = 1.6 mA
Output high voltage[3)] ($\overline{\text{PORT0}}$, $\overline{\text{PORT1}}$, Port 4, ALE, $\overline{\text{RD}}$, $\overline{\text{WR}}$, $\overline{\text{BHE}}$, $\overline{\text{RSTOUT}}$)	V_{OH} CC	2.4	–	V	I_{OH} = -2.4 mA
		0.9 V_{DD}	–	V	I_{OH} = -0.5 mA
Output high voltage[3)] (all other outputs)	V_{OH1} CC	2.4	–	V	I_{OH} = -1.6 mA
		0.9 V_{DD}	–	V	I_{OH} = -0.5 mA
Input leakage current (Port 5)	I_{OZ1} CC	–	±200	nA	0 V < V_{IN} < V_{DD}
Input leakage current (all other)	I_{OZ2} CC	–	±500	nA	0.45 V < V_{IN} < V_{DD}
$\overline{\text{RSTIN}}$ inactive current[4)]	I_{RSTH}[5)]	–	-10	µA	V_{IN} = V_{IH1}

DC Characteristics (Reduced Supply Voltage Range)

(Operating Conditions apply)[1)]

Parameter	Symbol		Limit Values		Unit	Test Condition
			min.	max.		
Input low voltage (TTL, all except XTAL1)	V_{IL}	SR	-0.5	0.8	V	–
Input low voltage XTAL1	V_{IL2}	SR	-0.5	0.3 V_{DD}	V	–
Input high voltage (TTL, all except $\overline{RSTIN}$ and XTAL1)	V_{IH}	SR	1.8	V_{DD} + 0.5	V	–
Input high voltage $\overline{RSTIN}$ (when operated as input)	V_{IH1}	SR	0.6 V_{DD}	V_{DD} + 0.5	V	–
Input high voltage XTAL1	V_{IH2}	SR	0.7 V_{DD}	V_{DD} + 0.5	V	–
Output low voltage (PORT0, PORT1, Port 4, ALE, $\overline{RD}$, $\overline{WR}$, $\overline{BHE}$, $\overline{RSTOUT}$, $\overline{RSTIN}$[2)])	V_{OL}	CC	–	0.45	V	I_{OL} = 1.6 mA
Output low voltage (all other outputs)	V_{OL1}	CC	–	0.45	V	I_{OL} = 1.0 mA
Output high voltage[3)] (PORT0, PORT1, Port 4, ALE, $\overline{RD}$, $\overline{WR}$, $\overline{BHE}$, $\overline{RSTOUT}$)	V_{OH}	CC	0.9 V_{DD}	–	V	I_{OH} = -0.5 mA
Output high voltage[3)] (all other outputs)	V_{OH1}	CC	0.9 V_{DD}	–	V	I_{OH} = -0.25 mA
Input leakage current (Port 5)	I_{OZ1}	CC	–	±200	nA	0 V < V_{IN} < V_{DD}
Input leakage current (all other)	I_{OZ2}	CC	–	±500	nA	0.45 V < V_{IN} < V_{DD}
$\overline{RSTIN}$ inactive current[4)]	I_{RSTH}[5)]		–	-10	µA	V_{IN} = V_{IH1}
$\overline{RSTIN}$ active current[4)]	I_{RSTL}[6)]		-100	–	µA	V_{IN} = V_{IL}
$\overline{RD}$/$\overline{WR}$ inact. current[7)]	I_{RWH}[5)]		–	-10	µA	V_{OUT} = 2.4 V
$\overline{RD}$/$\overline{WR}$ active current[7)]	I_{RWL}[6)]		-500	–	µA	V_{OUT} = V_{OLmax}
ALE inactive current[7)]	I_{ALEL}[5)]		–	20	µA	V_{OUT} = V_{OLmax}
ALE active current[7)]	I_{ALEH}[6)]		500	–	µA	V_{OUT} = 2.4 V
Port 6 inactive current[7)]	I_{P6H}[5)]		–	-10	µA	V_{OUT} = 2.4 V
Port 6 active current[7)]	I_{P6L}[6)]		-500	–	µA	V_{OUT} = V_{OL1max}

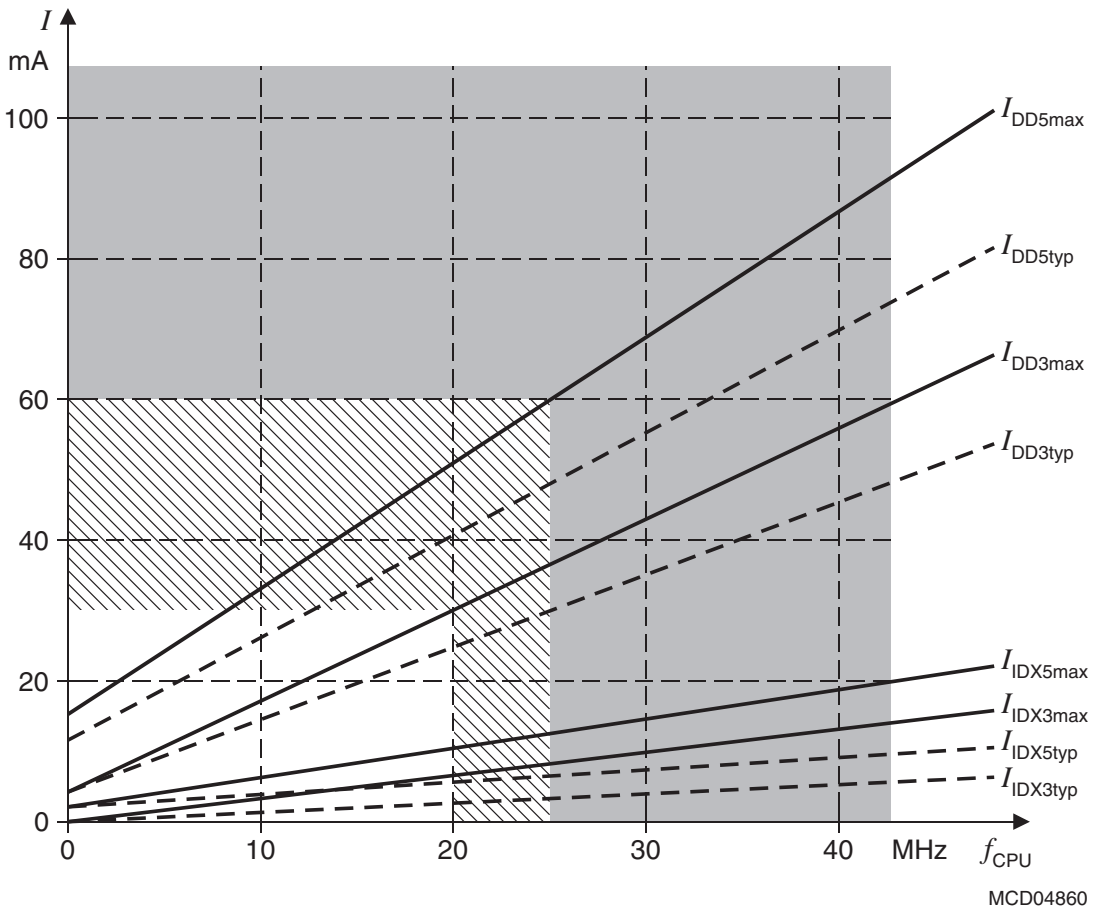

Figure 7 Supply/Idle Current as a Function of Operating Frequency

Table 9 C161K/O Clock Generation Modes

CLKCFG (P0H.7-5)	CPU Frequency $f_{CPU} = f_{OSC} \times F$	External Clock Input Range	Notes
0 X X	$f_{OSC} \times 1$	1 to 25 MHz	Direct drive[1)]
1 X X	f_{OSC} / 2	2 to 50 MHz	CPU clock via prescaler

1) The maximum frequency depends on the duty cycle of the external clock signal.

Prescaler Operation

When prescaler operation is configured (CLKCFG = $1XX_B$) the CPU clock is derived from the internal oscillator (input clock signal) by a 2:1 prescaler.
The frequency of f_{CPU} is half the frequency of f_{OSC} and the high and low time of f_{CPU} (i.e. the duration of an individual TCL) is defined by the period of the input clock f_{OSC}.

The timings listed in the AC Characteristics that refer to TCLs therefore can be calculated using the period of f_{OSC} for any TCL.

Direct Drive

When direct drive is configured (CLKCFG = $0XX_B$) the CPU clock is directly driven from the internal oscillator with the input clock signal.
The frequency of f_{CPU} directly follows the frequency of f_{OSC} so the high and low time of f_{CPU} (i.e. the duration of an individual TCL) is defined by the duty cycle of the input clock f_{OSC}.
The timings listed below that refer to TCLs therefore must be calculated using the minimum TCL that is possible under the respective circumstances. This minimum value can be calculated via the following formula:

$$TCL_{min} = 1/f_{OSC} \times DC_{min} \qquad \text{(DC = duty cycle)}$$

For two consecutive TCLs the deviation caused by the duty cycle of f_{OSC} is compensated so the duration of 2TCL is always $1/f_{OSC}$. The minimum value TCL_{min} therefore has to be used only once for timings that require an odd number of TCLs (1, 3, …). Timings that require an even number of TCLs (2, 4, …) may use the formula $2TCL = 1/f_{OSC}$.

AC Characteristics

Table 10 External Clock Drive XTAL1 (Standard Supply Voltage Range)
(Operating Conditions apply)

Parameter	Symbol		Direct Drive 1:1		Prescaler 2:1		Unit
			min.	max.	min.	max.	
Oscillator period	t_{OSC}	SR	40	–	20	–	ns
High time[1]	t_1	SR	20[2]	–	6	–	ns
Low time[1]	t_2	SR	20[2]	–	6	–	ns
Rise time[1]	t_3	SR	–	10	–	6	ns
Fall time[1]	t_4	SR	–	10	–	6	ns

1) The clock input signal must reach the defined levels V_{IL2} and V_{IH2}.

2) The minimum high and low time refers to a duty cycle of 50%. The maximum operating frequency (f_{CPU}) in direct drive mode depends on the duty cycle of the clock input signal.

Table 11 External Clock Drive XTAL1 (Reduced Supply Voltage Range)
(Operating Conditions apply)

Parameter	Symbol		Direct Drive 1:1		Prescaler 2:1		Unit
			min.	max.	min.	max.	
Oscillator period	t_{OSC}	SR	50	–	25	–	ns
High time[1]	t_1	SR	25[2]	–	8	–	ns
Low time[1]	t_2	SR	25[2]	–	8	–	ns
Rise time[1]	t_3	SR	–	10	–	6	ns
Fall time[1]	t_4	SR	–	10	–	6	ns

1) The clock input signal must reach the defined levels V_{IL2} and V_{IH2}.

2) The minimum high and low time refers to a duty cycle of 50%. The maximum operating frequency (f_{CPU}) in direct drive mode depends on the duty cycle of the clock input signal.

Multiplexed Bus (Reduced Supply Voltage Range) (cont'd)
(Operating Conditions apply)
ALE cycle time = 6 TCL + $2t_A + t_C + t_F$ (150 ns at 20 MHz CPU clock without waitstates)

Parameter	Symbol		Max. CPU Clock = 20 MHz		Variable CPU Clock 1 / 2TCL = 1 to 20 MHz		Unit
			min.	max.	min.	max.	
Data float after $\overline{RD}$	t_{19}	SR	–	36 + t_F	–	2TCL - 14 + t_F	ns
Data valid to $\overline{WR}$	t_{22}	CC	24 + t_C	–	2TCL - 26 + t_C	–	ns
Data hold after $\overline{WR}$	t_{23}	CC	36 + t_F	–	2TCL - 14 + t_F	–	ns
ALE rising edge after $\overline{RD}$, $\overline{WR}$	t_{25}	CC	36 + t_F	–	2TCL - 14 + t_F	–	ns
Address hold after $\overline{RD}$, $\overline{WR}$	t_{27}	CC	36 + t_F	–	2TCL - 14 + t_F	–	ns
ALE falling edge to $\overline{CS}$[1)]	t_{38}	CC	-8 - t_A	10 - t_A	-8 - t_A	10 - t_A	ns
$\overline{CS}$ low to Valid Data In[1)]	t_{39}	SR	–	47+ t_C + $2t_A$	–	3TCL - 28 + t_C + $2t_A$	ns
$\overline{CS}$ hold after $\overline{RD}$, $\overline{WR}$[1)]	t_{40}	CC	57 + t_F	–	3TCL - 18 + t_F	–	ns
ALE fall. edge to $\overline{RdCS}$, $\overline{WrCS}$ (with RW delay)	t_{42}	CC	19 + t_A	–	TCL - 6 + t_A	–	ns
ALE fall. edge to $\overline{RdCS}$, $\overline{WrCS}$ (no RW delay)	t_{43}	CC	-6 + t_A	–	-6 + t_A	–	ns
Address float after $\overline{RdCS}$, $\overline{WrCS}$ (with RW delay)	t_{44}	CC	–	0	–	0	ns
Address float after $\overline{RdCS}$, $\overline{WrCS}$ (no RW delay)	t_{45}	CC	–	25	–	TCL	ns
$\overline{RdCS}$ to Valid Data In (with RW delay)	t_{46}	SR	–	20 + t_C	–	2TCL - 30 + t_C	ns
$\overline{RdCS}$ to Valid Data In (no RW delay)	t_{47}	SR	–	45 + t_C	–	3TCL - 30 + t_C	ns
$\overline{RdCS}$, $\overline{WrCS}$ Low Time (with RW delay)	t_{48}	CC	38 + t_C	–	2TCL - 12 + t_C	–	ns
$\overline{RdCS}$, $\overline{WrCS}$ Low Time (no RW delay)	t_{49}	CC	63 + t_C	–	3TCL - 12 + t_C	–	ns

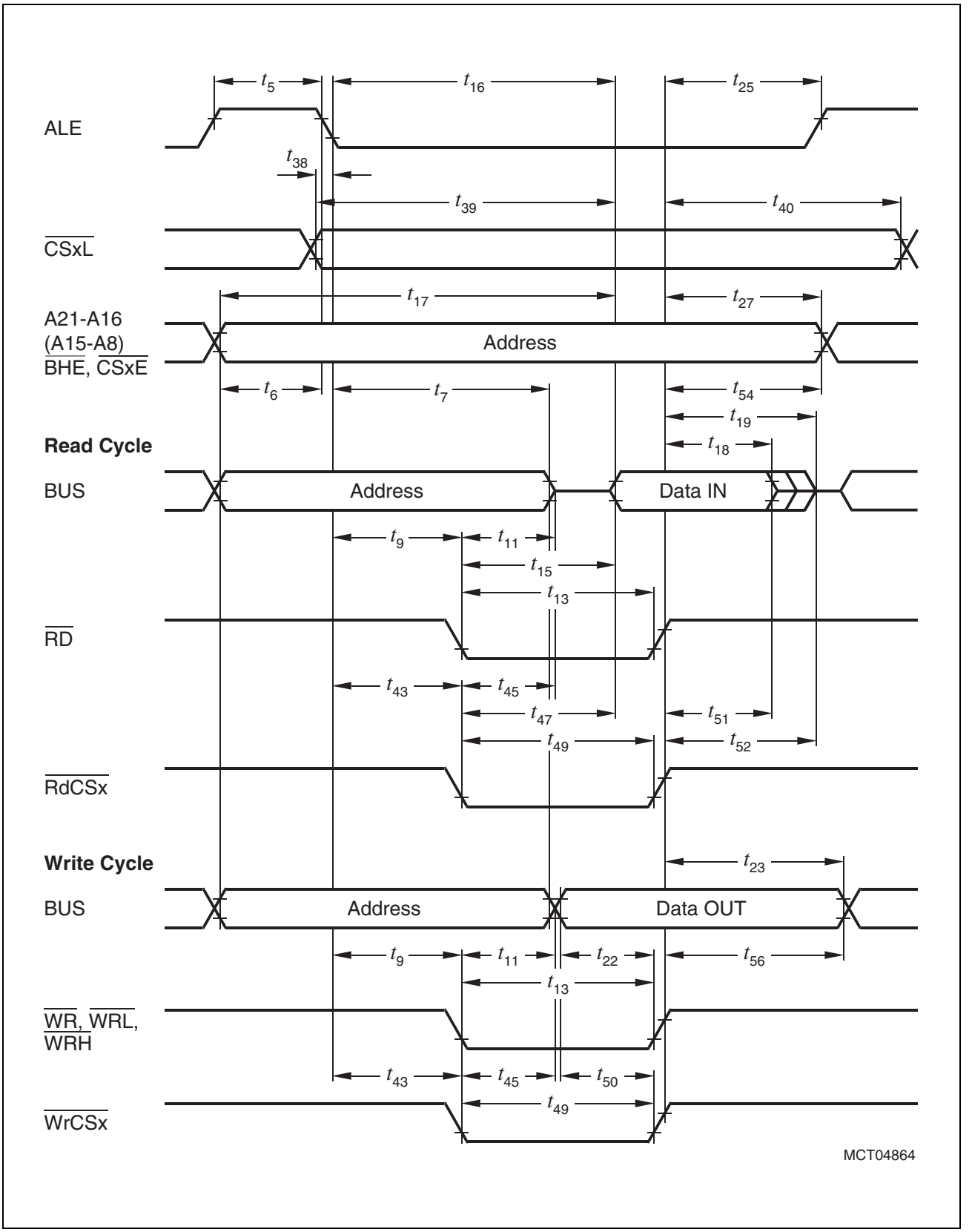

**Figure 15 External Memory Cycle:
Multiplexed Bus, No Read/Write Delay, Extended ALE**

AC Characteristics

Demultiplexed Bus (Standard Supply Voltage Range)

(Operating Conditions apply)
ALE cycle time = 4 TCL + 2t_A + t_C + t_F (80 ns at 25 MHz CPU clock without waitstates)

Parameter	Symbol		Max. CPU Clock = 25 MHz		Variable CPU Clock 1 / 2TCL = 1 to 25 MHz		Unit
			min.	max.	min.	max.	
ALE high time	t_5	CC	10 + t_A	–	TCL - 10 + t_A	–	ns
Address setup to ALE	t_6	CC	4 + t_A	–	TCL - 16 + t_A	–	ns
ALE falling edge to $\overline{RD}$, $\overline{WR}$ (with RW-delay)	t_8	CC	10 + t_A	–	TCL - 10 + t_A	–	ns
ALE falling edge to $\overline{RD}$, $\overline{WR}$ (no RW-delay)	t_9	CC	-10 + t_A	–	-10 + t_A	–	ns
$\overline{RD}$, $\overline{WR}$ low time (with RW-delay)	t_{12}	CC	30 + t_C	–	2TCL - 10 + t_C	–	ns
$\overline{RD}$, $\overline{WR}$ low time (no RW-delay)	t_{13}	CC	50 + t_C	–	3TCL - 10 + t_C	–	ns
$\overline{RD}$ to valid data in (with RW-delay)	t_{14}	SR	–	20 + t_C	–	2TCL - 20 + t_C	ns
$\overline{RD}$ to valid data in (no RW-delay)	t_{15}	SR	–	40 + t_C	–	3TCL - 20 + t_C	ns
ALE low to valid data in	t_{16}	SR	–	40 + t_A + t_C	–	3TCL - 20 + t_A + t_C	ns
Address to valid data in	t_{17}	SR	–	50 + 2t_A + t_C	–	4TCL - 30 + 2t_A + t_C	ns
Data hold after $\overline{RD}$ rising edge	t_{18}	SR	0	–	0	–	ns
Data float after $\overline{RD}$ rising edge (with RW-delay[1)])	t_{20}	SR	–	26 + 2t_A + t_F[1)]	–	2TCL - 14 + 22t_A + t_F[1)]	ns
Data float after $\overline{RD}$ rising edge (no RW-delay[1)])	t_{21}	SR	–	10 + 2t_A + t_F[1)]	–	TCL - 10 + 22t_A + t_F[1)]	ns

Demultiplexed Bus (Standard Supply Voltage Range) (cont'd)
(Operating Conditions apply)
ALE cycle time = 4 TCL + $2t_A$ + t_C + t_F (80 ns at 25 MHz CPU clock without waitstates)

Parameter	Symbol		Max. CPU Clock = 25 MHz		Variable CPU Clock 1 / 2TCL = 1 to 25 MHz		Unit
			min.	max.	min.	max.	
Data valid to $\overline{WR}$	t_{22}	CC	20 + t_C	–	2TCL - 20 + t_C	–	ns
Data hold after $\overline{WR}$	t_{24}	CC	10 + t_F	–	TCL - 10 + t_F	–	ns
ALE rising edge after $\overline{RD}$, $\overline{WR}$	t_{26}	CC	-10 + t_F	–	-10 + t_F	–	ns
Address hold after $\overline{WR}$[2]	t_{28}	CC	0 + t_F	–	0 + t_F	–	ns
ALE falling edge to $\overline{CS}$[3]	t_{38}	CC	-4 - t_A	10 - t_A	-4 - t_A	10 - t_A	ns
$\overline{CS}$ low to Valid Data In[3]	t_{39}	SR	–	40 + t_C + $2t_A$	–	3TCL - 20 + t_C + $2t_A$	ns
$\overline{CS}$ hold after $\overline{RD}$, $\overline{WR}$[3]	t_{41}	CC	6 + t_F	–	TCL - 14 + t_F	–	ns
ALE falling edge to $\overline{RdCS}$, $\overline{WrCS}$ (with RW-delay)	t_{42}	CC	16 + t_A	–	TCL - 4 + t_A	–	ns
ALE falling edge to $\overline{RdCS}$, $\overline{WrCS}$ (no RW-delay)	t_{43}	CC	-4 + t_A	–	-4 + t_A	–	ns
$\overline{RdCS}$ to Valid Data In (with RW-delay)	t_{46}	SR	–	16 + t_C	–	2TCL - 24 + t_C	ns
$\overline{RdCS}$ to Valid Data In (no RW-delay)	t_{47}	SR	–	36 + t_C	–	3TCL - 24 + t_C	ns
$\overline{RdCS}$, $\overline{WrCS}$ Low Time (with RW-delay)	t_{48}	CC	30 + t_C	–	2TCL - 10 + t_C	–	ns
$\overline{RdCS}$, $\overline{WrCS}$ Low Time (no RW-delay)	t_{49}	CC	50 + t_C	–	3TCL - 10 + t_C	–	ns
Data valid to $\overline{WrCS}$	t_{50}	CC	26 + t_C	–	2TCL - 14 + t_C	–	ns
Data hold after $\overline{RdCS}$	t_{51}	SR	0	–	0	–	ns

Demultiplexed Bus (Standard Supply Voltage Range) (cont'd)
(Operating Conditions apply)
ALE cycle time = 4 TCL + 2t_A + t_C + t_F (80 ns at 25 MHz CPU clock without waitstates)

Parameter	Symbol		Max. CPU Clock = 25 MHz		Variable CPU Clock 1 / 2TCL = 1 to 25 MHz		Unit
			min.	max.	min.	max.	
Data float after $\overline{\text{RdCS}}$ (with RW-delay)[1]	t_{53}	SR	–	20 + t_F	–	2TCL - 20 + 2t_A + t_F [1]	ns
Data float after $\overline{\text{RdCS}}$ (no RW-delay)[1]	t_{68}	SR	–	0 + t_F	–	TCL - 20 + 2t_A + t_F [1]	ns
Address hold after $\overline{\text{RdCS}}$, $\overline{\text{WrCS}}$	t_{55}	CC	-6 + t_F	–	-6 + t_F	–	ns
Data hold after $\overline{\text{WrCS}}$	t_{57}	CC	6 + t_F	–	TCL - 14 + t_F	–	ns

1) RW-delay and t_A refer to the next following bus cycle (including an access to an on-chip X-Peripheral).

2) Read data are latched with the same clock edge that triggers the address change and the rising $\overline{\text{RD}}$ edge. Therefore address changes before the end of $\overline{\text{RD}}$ have no impact on read cycles.

3) These parameters refer to the latched chip select signals ($\overline{\text{CSxL}}$). The early chip select signals ($\overline{\text{CSxE}}$) are specified together with the address and signal $\overline{\text{BHE}}$ (see figures below).

Demultiplexed Bus (Reduced Supply Voltage Range) (cont'd)
(Operating Conditions apply)
ALE cycle time = 4 TCL + 2t_A + t_C + t_F (100 ns at 20 MHz CPU clock without waitstates)

Parameter	Symbol		Max. CPU Clock = 20 MHz		Variable CPU Clock 1 / 2TCL = 1 to 20 MHz		Unit
			min.	max.	min.	max.	
Data float after $\overline{\text{RdCS}}$ (with RW-delay)[1]	t_{53}	SR	–	30 + t_F	–	2TCL - 20 + 2t_A + t_F [1]	ns
Data float after $\overline{\text{RdCS}}$ (no RW-delay)[1]	t_{68}	SR	–	5 + t_F	–	TCL - 20 + 2t_A + t_F [1]	ns
Address hold after $\overline{\text{RdCS}}$, $\overline{\text{WrCS}}$	t_{55}	CC	-16 + t_F	–	-16 + t_F	–	ns
Data hold after $\overline{\text{WrCS}}$	t_{57}	CC	9 + t_F	–	TCL - 16 + t_F	–	ns

1) RW-delay and t_A refer to the next following bus cycle (including an access to an on-chip X-Peripheral).

2) Read data are latched with the same clock edge that triggers the address change and the rising $\overline{\text{RD}}$ edge. Therefore address changes before the end of $\overline{\text{RD}}$ have no impact on read cycles.

3) These parameters refer to the latched chip select signals ($\overline{\text{CSxL}}$). The early chip select signals ($\overline{\text{CSxE}}$) are specified together with the address and signal $\overline{\text{BHE}}$ (see figures below).

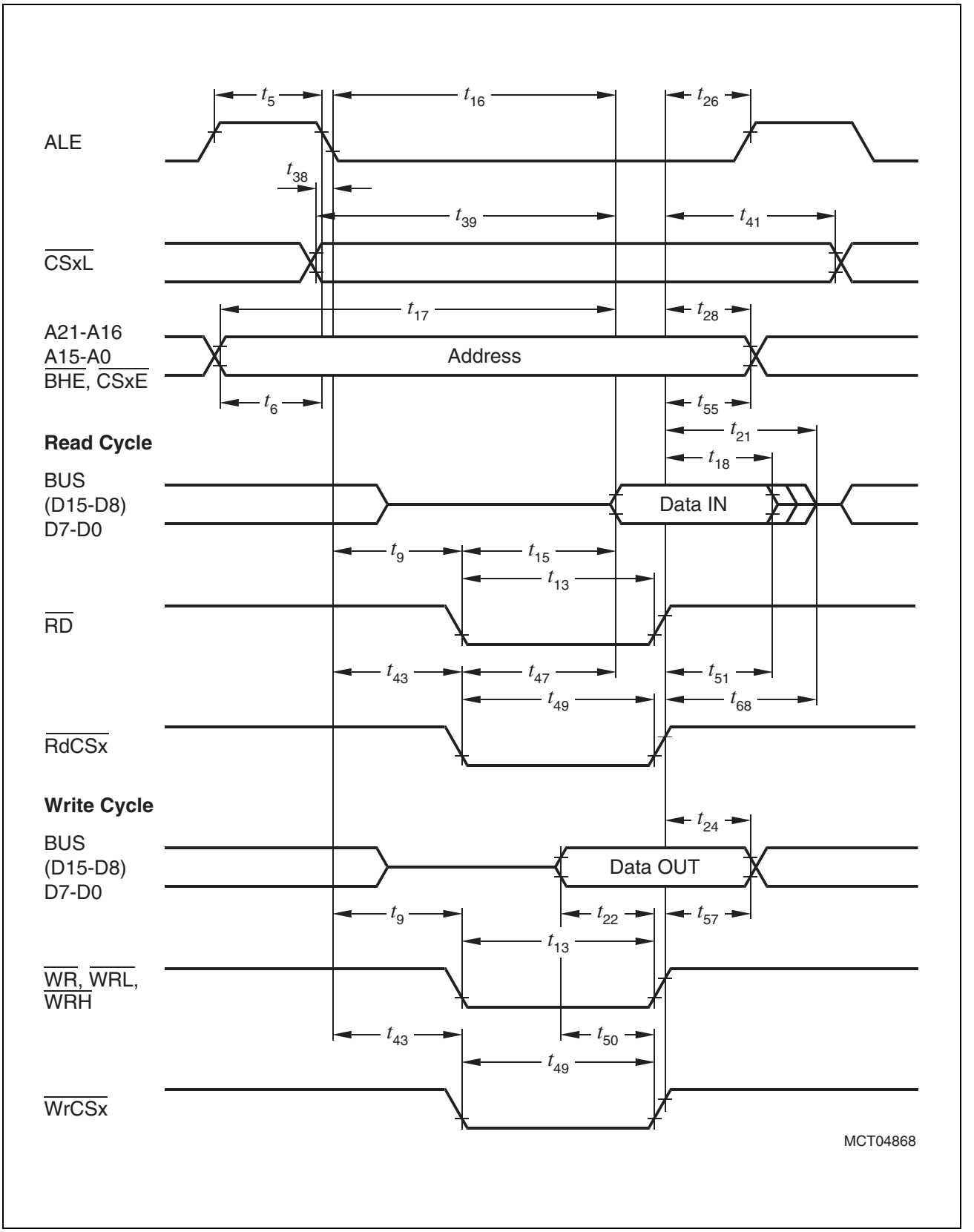

**Figure 19 External Memory Cycle:
Demultiplexed Bus, No Read/Write Delay, Extended ALE**

Infineon goes for Business Excellence

“Business excellence means intelligent approaches and clearly defined processes, which are both constantly under review and ultimately lead to good operating results.
Better operating results and business excellence mean less idleness and wastefulness for all of us, more professional success, more accurate information, a better overview and, thereby, less frustration and more satisfaction.”

Dr. Ulrich Schumacher

http://www.infineon.com

Published by Infineon Technologies AG